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Vishay Siliconix

Automotive N-Channel 40 V (D-S) 175 °C MOSFET



Marking code: Q050

PRODUCT SUMMARY				
V _{DS} (V)	40			
$R_{DS(on)}$ (Ω) at $V_{GS} = 4.5 \text{ V}$	0.0065			
$R_{DS(on)}(\Omega)$ at $V_{GS} = 10 \text{ V}$	0.0045			
I _D (A) ^e	86			
Configuration	Single			

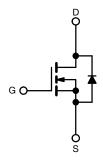
FEATURES

- TrenchFET® Gen IV power MOSFET
- AEC-Q101 qualified
- 100 % R_q and UIS tested
- · Wettable flank terminals
- Low thermal resistance with 0.75 mm profile

 Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



HALOGEN FREE



N-Channel MOSFET

ORDERING INFORMATION	
Package	PowerPAK® 1212-8SLW
Lead (Pb)-free and halogen-free	SQS142ELNW (for detailed order number please see www.vishay.com/doc?79771)

ABSOLUTE MAXIMUM RATING	GS (T _C = 25 °C, unless	s otherwise noted	d)		
PARAMETER		SYMBOL	LIMIT	UNIT	
Drain-source voltage		V _{DS}	40	.,,	
Gate-source voltage		V _{GS} ± 20		V	
Continuous drain current e	T _C = 25 °C		86		
	T _C = 125 °C	I _D	63		
Continuous source current (diode conduction) e		I _S	64	Α	
Pulsed drain current a, e		I _{DM}	271		
Single pulse avalanche current	L = 0.1 mH	I _{AS}	22.5		
Single pulse avalanche energy	L = 0.1 mn	E _{AS}	25.3	mJ	
Maximum power dissipation ^a	T _C = 25 °C	P _D	70	W	
	T _C = 125 °C		23		
Operating junction and storage temperature range		T _J , T _{stg}	-55 to +175	°C	
Soldering recommendations (peak temperature) c		-	260		

THERMAL RESISTANCE RATINGS					
PARAMETER		SYMBOL	LIMIT	UNIT	
Junction-to-ambient	PCB mount b	R_{thJA}	54	°C/W	
Junction-to-case (drain) ^d		R_{thJC}	2.1		

Notes

- a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %
- b. When mounted on 1" square PCB (FR4 material)
- c. See solder profile (www.vishay.com/doc?73257). A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection
- d. As per on JESD51-14
- e. Values based on RthJC and TC 25 °C. Actual values achievable will be dependent on the thermal characteristics of the complete system

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PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
Static							
Drain-source breakdown voltage	V_{DS}	$V_{GS} = 0$, $I_D = 250 \mu A$		40	-	-	V
Gate-source threshold voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250 \mu A$		1.2	1.7	2.5	V
Gate-source leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$		-	-	± 100	nA
		$V_{GS} = 0 V$	V _{DS} = 40 V	-	- 1		
Zero gate voltage drain current	I _{DSS}	V _{GS} = 0 V	V _{DS} = 40 V, T _J = 125 °C	-	-	50	μA
		V _{GS} = 0 V	V _{DS} = 40 V, T _J = 175 °C	-	-	150	
On-state drain current ^a	I _{D(on)}	V _{GS} = 10 V	$V_{DS} \ge 5 \text{ V}$	20	-	-	Α
		V _{GS} = 4.5 V	1 40 4	-	0.0050	0.0065	
During a second of the second	$V_{GS} = 10 \text{ V}$ $I_D = 10 \text{ A}$	I _D = 10 A	-	0.0034	0.0045		
Drain-source on-state resistance ^a	R _{DS(on)}	V _{GS} = 10 V	I _D = 10 A, T _J = 125 °C	-	-	0.0078	Ω
		V _{GS} = 10 V	I _D = 10 A, T _J = 175 °C	-	-	0.0095	
Forward transconductance b	9 _{fs}	V_{DS}	= 15 V, I _D = 10 A	-	70	-	S
Dynamic ^b		•					
Input capacitance	C _{iss}	V _{GS} = 0 V	V _{DS} = 25 V, f = 1 MHz	-	1744	2442	pF
Output capacitance	C _{oss}			-	442	619	
Reverse transfer capacitance	C _{rss}			-	39	55	
Total gate charge ^c	Qg		V _{DS} = 20 V, I _D = 3 A	-	32	48	nC
Gate-source charge ^c	Q_{gs}	V _{GS} = 10 V		-	6	-	
Gate-drain charge ^c	Q _{gd}			-	6	-	
Gate resistance	R_g	f = 1 MHz		0.7	1.4	2.1	Ω
Turn-on delay time ^c	t _{d(on)}			-	11	17	
Rise time ^c	t _r	$V_{DD} = 20 \text{ V}, \text{ R}_L = 6.67 \Omega$ $I_D \cong 3 \text{ A}, \text{ V}_{GEN} = 10 \text{ V}, \text{ R}_g = 1 \Omega$		-	4	8	ns
Turn-off delay time ^c	t _{d(off)}			-	25	38	
Fall time ^c	t _f			-	6	9	
Source-Drain Diode Ratings and Charac	teristic ^b	•			•		
Pulsed current ^a	I _{SM}			-	-	271	Α
Forward voltage	V_{SD}	I _F = 10 A, V _{GS} = 0 V		-	0.82	1.1	V
Body diode reverse recovery time	t _{rr}	V_{DD} = 32 V, I_{FM} = 3 A, di/dt = 100 A/μs, R = 10 Ω, L = 0.3 mH, pulse width = 2 μs		-	27	54	ns
Body diode reverse recovery charge	Q _{rr}			-	19	38	nC
Reverse recovery fall time	ta			-	14	-	
Reverse recovery rise time	t _b			-	14	-	ns
Body diode peak reverse recovery current	I _{RM(REC)}			-	-1.2	-	Α

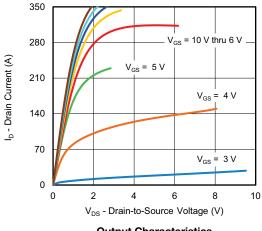
Notes

- a. Pulse test; pulse width $\leq 300~\mu s,~duty~cycle \leq 2~\%$
- b. Guaranteed by design, not subject to production testing
- c. Independent of operating temperature

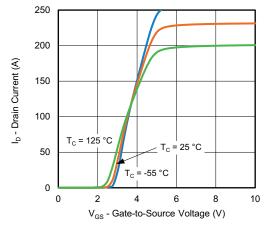
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



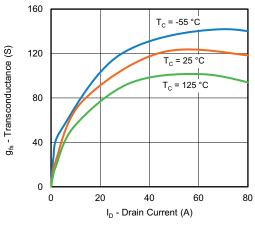
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



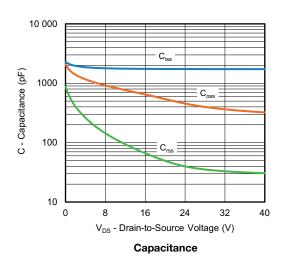




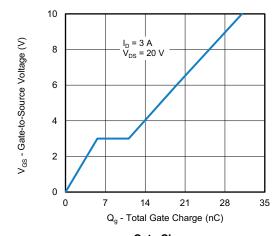
Transfer Characteristics



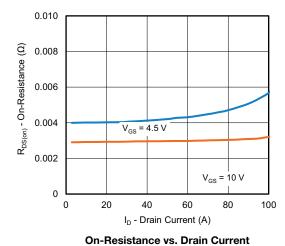
Transconductance





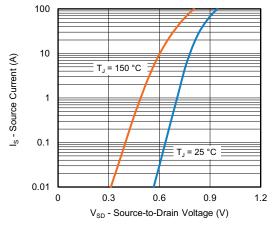


Gate Charge

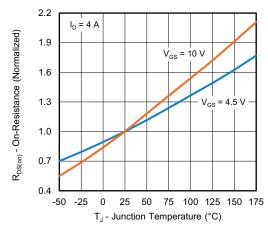




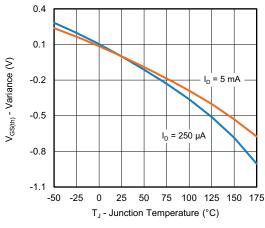
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



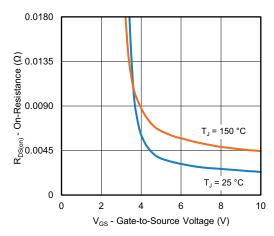
Source Drain Diode Forward Voltage



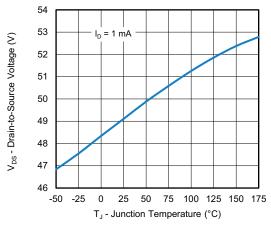
On-Resistance vs. Junction Temperature



Threshold Voltage



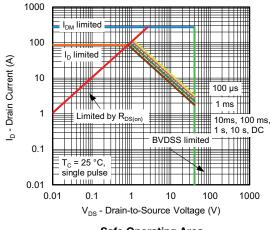
On-Resistance vs. Gate-to-Source Voltage



Drain Source Breakdown vs. Junction Temperature



THERMAL RATINGS ($T_A = 25$ °C, unless otherwise noted)



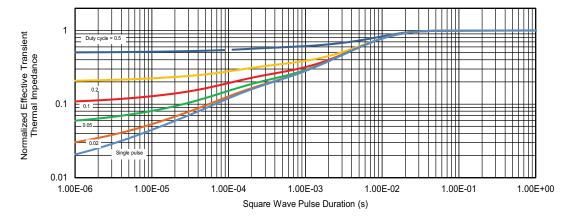
Safe Operating Area

Note

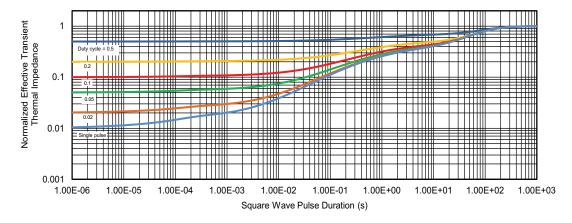
a. $V_{\text{GS}} > \text{minimum } V_{\text{GS}}$ at which $R_{\text{DS(on)}}$ is specified



THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case



Normalized Thermal Transient Impedance, Junction-to-Ambient

Note

- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
 - Normalized Transient Thermal Impedance Junction-to-Case (25 °C)

are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package / tape drawings, part marking, and reliability data, see www.vishay.com/ppg?63170.



RECOMMENDED MINIMUM PADS FOR PowerPAK® 1212-8 Single



Recommended Minimum Pads Dimensions in Inches/(mm)

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APPLICATION NOTE



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